

Comment on "Bose-Einstein condensation in low-dimensional traps"

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We show that the critical temperature of a one-dimensional gas confined by a power-law potential should be lower than that in the paper of Vanderlei Bagnato and Daniel Kleppner. Moreover, a sketch of the critical temperature is given in some more details.

The paper by Vanderlei Bagnato and Daniel Kleppner discusses the Bose-Einstein condensation of an ideal Bose gas confined by one- and two- dimensional traps [1]. This is an important work and the results are widely cited [2].

The density of states of a one-dimensional gas confined by a potential $U(x) = U_0(|x|/L)^\eta$ is

$$\begin{aligned}\rho(\varepsilon) &= \frac{\sqrt{2M}}{h} \int_{-l(\varepsilon)}^{l(\varepsilon)} \frac{dx}{\sqrt{\varepsilon - U(x)}} \\ &= \frac{2}{\eta} \frac{\sqrt{2M}}{h} L \frac{\varepsilon^{\frac{1}{\eta} - \frac{1}{2}}}{U_0^{\frac{1}{\eta}}} F(\eta),\end{aligned}$$

where $l(\varepsilon) = L(\frac{\varepsilon}{U_0})^{\frac{1}{\eta}}$, and

$$F(\eta) = \int_0^1 \frac{y^{\frac{1-\eta}{\eta}} dy}{\sqrt{1-y}} = \frac{\sqrt{\pi} \Gamma(\frac{1}{\eta})}{\Gamma(\frac{1}{\eta} - \frac{1}{2})}.$$

In ref. [1] the factor $\frac{2}{\eta}$ is lost.

The number of particles in the excited states is given by

$$\begin{aligned}N_e &= \int_0^\infty d\varepsilon \rho(\varepsilon) \frac{1}{e^{(\varepsilon-\mu)/kT} - 1} \\ &= \frac{2}{\eta} \frac{\sqrt{2M}}{h} L \frac{F(\eta)}{U_0^{\frac{1}{\eta}}} (kT)^{\frac{1}{\eta} + \frac{1}{2}} g_1(\eta, \frac{\mu}{kT}),\end{aligned}$$

where

$$g_1(\eta, x) = \int_0^\infty dy \frac{y^{\frac{1}{\eta} - \frac{1}{2}}}{e^{y-x} - 1}.$$

The Bose-Einstein condensation begins when N_e equals to the total number of particles in the system N . In this case the chemical potential $\mu = 0$. The critical temperature T_c^{1D} can be given by the expression:

$$kT_c^{1D} = \left(\frac{\eta}{2}\right)^{\frac{2\eta}{2+\eta}} \left[\frac{N}{L} \frac{h}{\sqrt{2M}} \frac{U_0^{\frac{1}{\eta}}}{F(\eta)} \frac{1}{g_1(\eta, 0)} \right]^{\frac{2\eta}{2+\eta}}.$$

As a result of adding $\frac{2}{\eta}$ in the density of states $\rho(\varepsilon)$, a factor $(\frac{\eta}{2})^{\frac{2\eta}{2+\eta}}$ appears in the expression of the critical temperature T_c^{1D} . According to the discussion in [1], the one-dimensional gas displays Bose-Einstein condensation

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only when the potential power $\eta < 2$. The value of the factor $\left(\frac{\eta}{2}\right)^{\frac{2\eta}{2+\eta}}$ is always less than 1 when $0 < \eta < 2$. Therefore, the critical temperature will be suppressed by such a factor. The variation of T_c^{1D} with η is shown in Fig1. In ref. [1], the curve of the critical temperature T_c^{1D} does not include the case of small η . This makes T_c^{1D} looks like a monotonically decreasing function of η . In Fig1, the dependence of T_c^{1D} on η is drawn in the whole interval $[0, 2]$. The critical temperature is found to show a peak between $\eta = 0$ and 2.

- [1] Vanderlei Bagnato and Daniel Kleppner, Phys. Rev. A **44**, 7439 (1991).
- [2] P. Nozières, in *Bose-Einstein condensation*, edited by A. Griffin, D. W. Snoke and S. Stringari (Cambridge University Press, Cambridge, UK, 1995)

Fig1. Critical temperature T_c^{1D} , as a function of the potential power η , for various values of U_0 ($U_0^a > U_0^b > U_0^c$).

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Fig 1.

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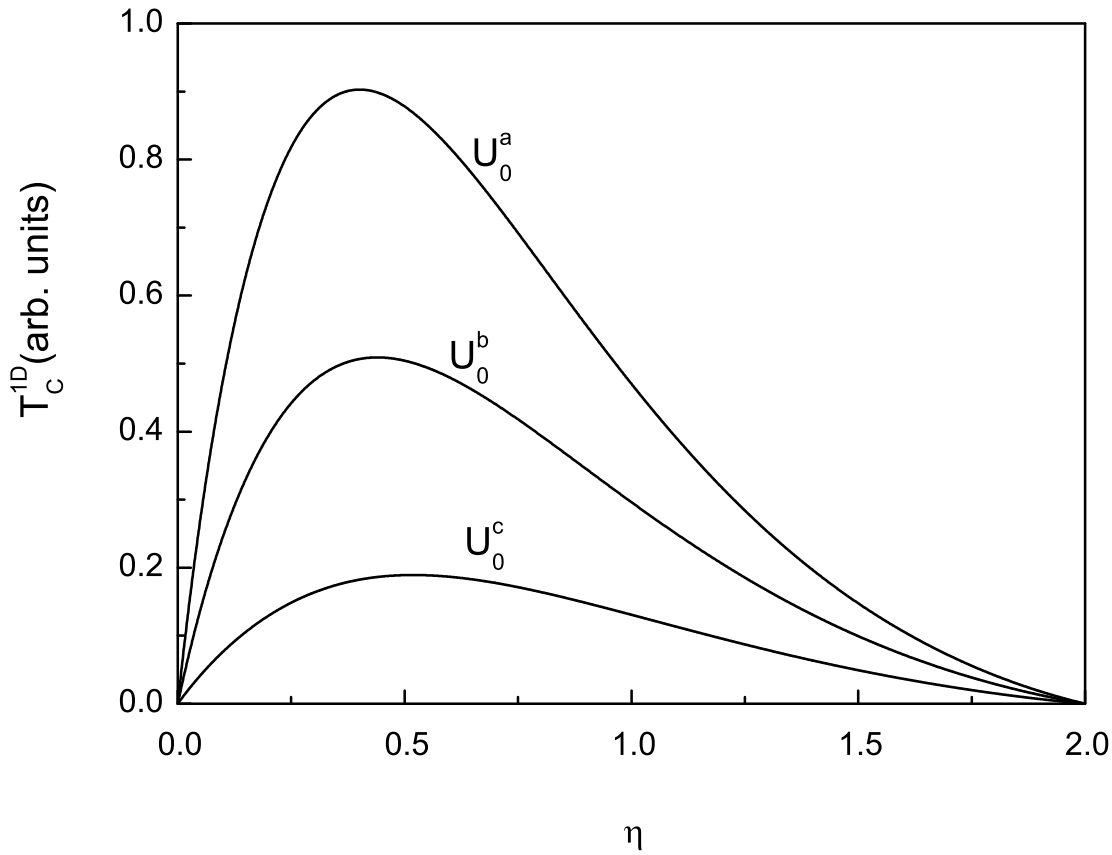


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